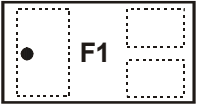
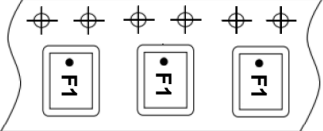
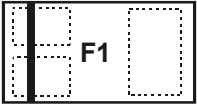
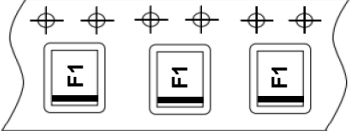
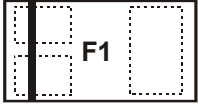
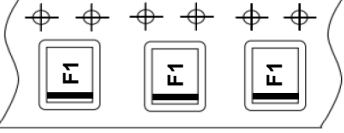


Marking Information

| | |
|----------------------------|--|
| <p>BC847BLP4-7</p> | <div style="display: flex; justify-content: space-around; align-items: flex-start;"> <div style="text-align: center;">  <p>Top View</p> <p>Dot Denotes Collector Side</p>  </div> <div style="text-align: center;"> <p>From date code 1527 (YYWW), this changes to:</p>  <p>Top View</p> <p>Bar Denotes Base and Emitter Side</p>  </div> </div> |
| <p>BC847BLP4-7B</p> | <div style="text-align: center;">  <p>Top View</p> <p>Bar Denotes Base and Emitter Side</p>  </div> <p style="text-align: right; margin-top: 20px;">F1 = Product Type Marking Code</p> |

Absolute Maximum Ratings (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

| Characteristic | Symbol | Value | Unit |
|------------------------------|-----------|-------|------|
| Collector-Base Voltage | V_{CBO} | 50 | V |
| Collector-Emitter Voltage | V_{CEO} | 45 | V |
| Emitter-Base Voltage | V_{EBO} | 6.0 | V |
| Collector Current | I_C | 100 | mA |
| Peak Pulse Collector Current | I_{CM} | 200 | mA |

Thermal Characteristics (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

| Characteristic | Symbol | Value | Unit |
|---|-----------------|-------------|--------------------|
| Power Dissipation | P_D | 400 | mW |
| (Note 5) | | 1000 | |
| Thermal Resistance, Junction to Ambient | $R_{\theta JA}$ | 310 | $^\circ\text{C/W}$ |
| (Note 6) | | 120 | |
| Thermal Resistance, Junction to Lead | $R_{\theta JL}$ | 120 | $^\circ\text{C/W}$ |
| Operating and Storage and Temperature Range | T_J, T_{STG} | -55 to +150 | $^\circ\text{C}$ |

ESD Ratings (Note 8)

| Characteristic | Symbol | Value | Unit | JEDEC Class |
|--|---------|-------|------|-------------|
| Electrostatic Discharge - Human Body Model | ESD HBM | 4,000 | V | 3A |
| Electrostatic Discharge - Machine Model | ESD MM | 200 | V | B |

Electrical Characteristics (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

| Characteristic | Symbol | Min | Typ | Max | Unit | Test Condition |
|---|---------------|----------|------------|------------|---------------------|---|
| Collector-Base Breakdown Voltage | BV_{CBO} | 50 | — | — | V | $I_C = 10\mu\text{A}, I_B = 0$ |
| Collector-Emitter Breakdown Voltage (Note 9) | BV_{CEO} | 45 | — | — | V | $I_C = 10\text{mA}, I_B = 0$ |
| Emitter-Base Breakdown Voltage | BV_{EBO} | 6 | — | — | V | $I_E = 1\mu\text{A}, I_C = 0$ |
| DC Current Gain | h_{FE} | 200 | 350 | 450 | — | $V_{CE} = 5\text{V}, I_C = 2\text{mA}$ |
| Collector-Emitter Saturation Voltage (Note 9) | $V_{CE(sat)}$ | — | 80 200 | 250 600 | mV | $I_C = 10\text{mA}, I_B = 0.5\text{mA}$ $I_C = 100\text{mA}, I_B = 5\text{mA}$ |
| Base-Emitter Saturation Voltage (Note 9) | $V_{BE(sat)}$ | — | 700 900 | — | mV | $I_C = 10\text{mA}, I_B = 0.5\text{mA}$ $I_C = 100\text{mA}, I_B = 5\text{mA}$ |
| Base-Emitter Voltage (Note 9) | $V_{BE(on)}$ | 580 — | 640 725 | 700 770 | mV | $V_{CE} = 5\text{V}, I_C = 2\text{mA}$ $V_{CE} = 5\text{V}, I_C = 10\text{mA}$ |
| Collector-Cutoff Current | I_{CBO} | — | — | 15 5 | nA μA | $V_{CB} = 30\text{V}$ $V_{CB} = 30\text{V}, T_A = +150^\circ\text{C}$ |
| Gain Bandwidth Product | f_T | 100 | — | — | MHz | $V_{CE} = 5\text{V}, I_C = 10\text{mA}$, $f = 100\text{MHz}$ |
| Collector-Base Capacitance | C_{CBO} | — | 3 | — | pF | $V_{CB} = 10\text{V}, f = 1\text{MHz}$ |

- Notes:
5. For a device mounted on the minimum recommended pad layout of 1oz copper on a single-sided 1.6mm FR4 PCB; device is measured under still-air conditions whilst operating in steady-state condition. The entire exposed collector pad is attached to the heatsink.
 6. Same as Note 5, except the exposed collector pad is mounted on 25mm x 25mm 2oz copper.
 7. Thermal resistance from junction to solder-point (on the exposed collector pad).
 8. Refer to JEDEC specification JESD22-A114 and JESD22-A115.
 9. Measured under pulsed conditions. Pulse width $\leq 300\mu\text{s}$. Duty cycle $\leq 2\%$.

Typical Electrical Characteristics (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

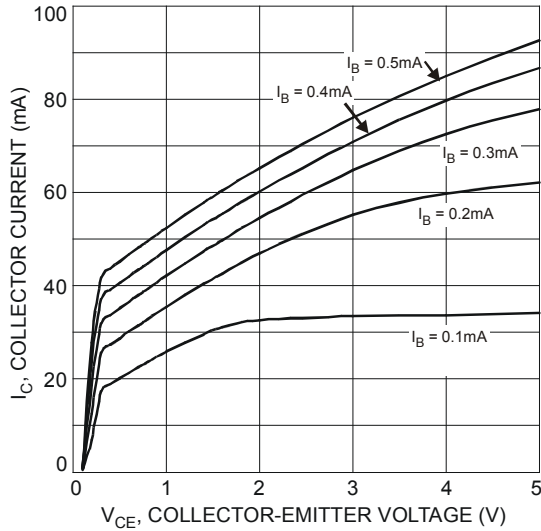


Fig. 2 Typical Collector Current vs. Collector-Emitter Voltage

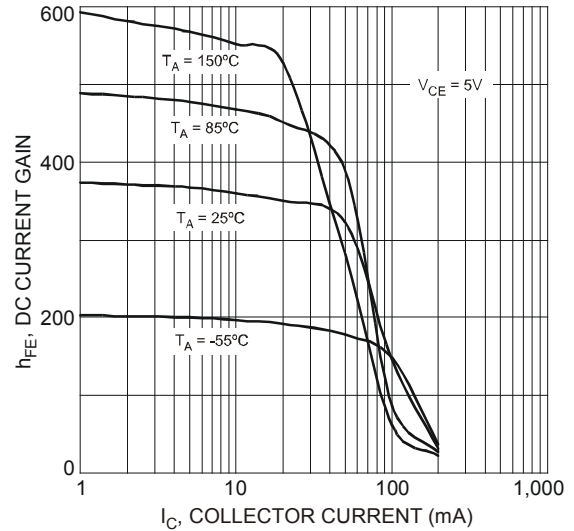


Fig. 3 Typical DC Current Gain vs. Collector Current

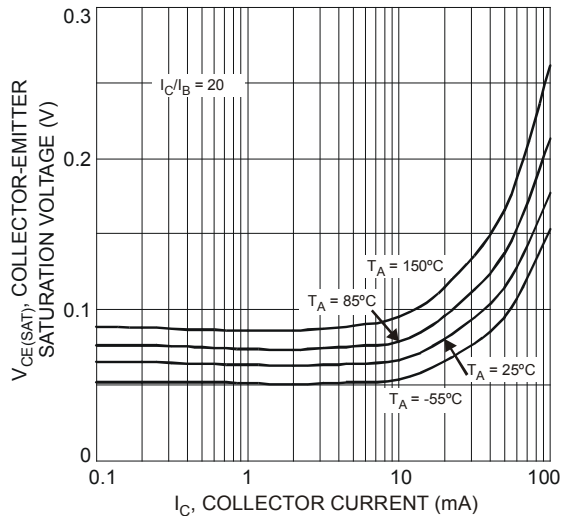


Fig. 4 Typical Collector-Emitter Saturation Voltage vs. Collector Current

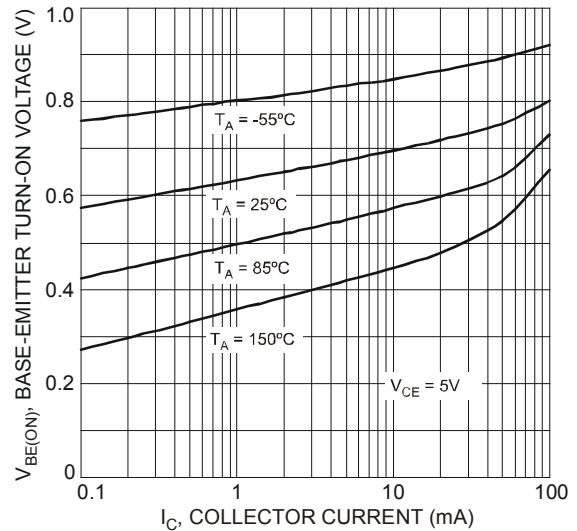


Fig. 5 Typical Base-Emitter Turn-On Voltage vs. Collector Current

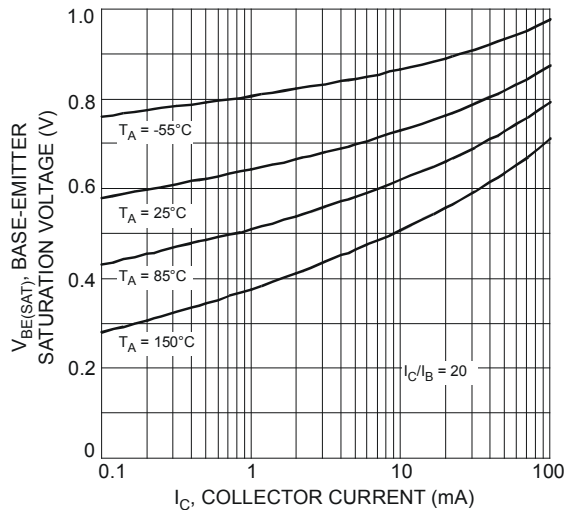
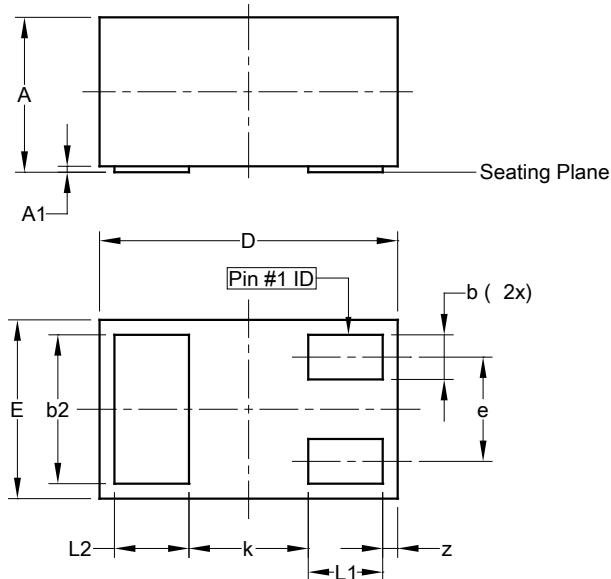


Fig. 6 Typical Base-Emitter Saturation Voltage vs. Collector Current

Package Outline Dimensions

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

X2-DFN1006-3

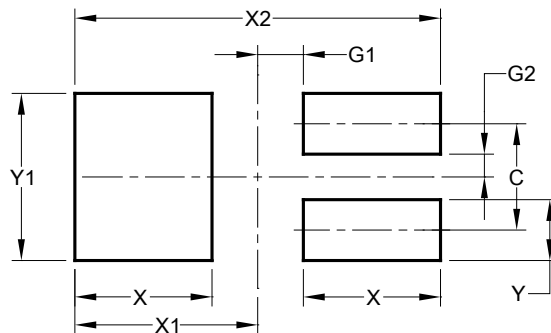


| X2-DFN1006-3 | | | |
|----------------------|------|------|------|
| Dim | Min | Max | Typ |
| A | — | 0.40 | — |
| A1 | 0.00 | 0.05 | 0.03 |
| b | 0.10 | 0.20 | 0.15 |
| b2 | 0.45 | 0.55 | 0.50 |
| D | 0.95 | 1.05 | 1.00 |
| E | 0.55 | 0.65 | 0.60 |
| e | - | - | 0.35 |
| L1 | 0.20 | 0.30 | 0.25 |
| L2 | 0.20 | 0.30 | 0.25 |
| k | - | - | 0.40 |
| z | 0.02 | 0.08 | 0.05 |
| All Dimensions in mm | | | |

Suggested Pad Layout

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

X2-DFN1006-3



| Dimensions | Value (in mm) |
|------------|---------------|
| C | 0.350 |
| G1 | 0.150 |
| G2 | 0.075 |
| X | 0.450 |
| X1 | 0.600 |
| X2 | 1.200 |
| Y | 0.200 |
| Y1 | 0.550 |

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